Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.000 inches

Overall Diameter:

0.375 inches

End Application:

Control-inter e/i fscm 26401

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Quality assurance level tx and burn in and hermetically sealed case and reverse polarity

Overall Width Across Flats:

0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

13.7 breakdown voltage, dc

Current Rating Per Characteristic:

3750.00 milliamperes source cutoff current horsepower metric

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

Test Data Document:

81349-mil-s-19500/358 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain

environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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